Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S88	1	"5795385".pn. and (laser or electron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:15
S90	40	optical near2 (cvd or chemical near2 vapor near2 deposition) near10 (silicon or si) near5 amorphous	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:16
S89	156	optical near2 (cvd or chemical near2 vapor near2 deposition) near10 (silicon or si)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:16
S91	6	optical near2 (cvd or chemical near2 vapor near2 deposition) near10 (silicon or si) near5 amorphous same ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:17
S94	762	(si or silicon) near16 laser near15 crystal\$7 same ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:20
S93	7443	(si or silicon) near16 laser near15 crystal\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:20
S92	23	optical near2 (cvd or chemical near2 vapor near2 deposition) near10 (silicon or si) same ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:20
S95	440	(si or silicon) near16 laser near15 crystal\$7 same ion and @py<"2002"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 11:21
S96	382	(si or silicon) near16 laser near15 crystal\$7 same ion and @py<"2001"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:22

S97	229	(si or silicon) near15 plasma near10 ion near2 beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:23
S99	1812	plasma near15 cvd and (si or silicon) near15 laser near2 anneal\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:25
S10 1	443	(si or silicon) near15 (cvd or chemical near2 vapor near2 depostion) near5 plasma near10 ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:26
S10 0	49	plasma near15 cvd near16 ion near15 (silicon or si) and (si or silicon) near15 laser near2 anneal\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:26
S98	20	(si or silicon) near15 (cvd or chemical near2 vapor near2 depostion) near5 plasma near10 ion near2 beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/13 14:26
S10 2	5305	(cvd or chemical near2 vapor near2 deposit\$6) same ion near5 beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 13:31
S10 3	5	(cvd or chemical near2 vapor near2 deposit\$6) same ion near5 beam and 117/1-4.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/02/16 14:32
S10 5	2270	sputter\$5 near10 (si or silicon) and laser near5 crystal\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:36
S10 4	26303	sputter\$5 near10 (si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:36
S10 7	301	sputter\$5 near10 (si or silicon) same ion and laser near5 (crystal\$7 or recrystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:37

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S10 9	3987	shunpei near2 yamazaki.in. and (crystal\$7 or recrystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:43
S10 8	162	sputter\$5 near10 (si or silicon) same ion and laser near5 (crystal\$7 or recrystal\$6) and @py<"2003"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:43
S11 0	1331	shunpei near2 yamazaki.in. and (crystal\$7 or recrystal\$6) near5 laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:47
S11 1	8	S110 and ion near10 (si or silicon) near5 polycrystal\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 14:58
S10 6	2349	sputter\$5 near10 (si or silicon) and laser near5 (crystal\$7 or recrystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 15:02
S11 3	324	crucible near2 (rais\$4 or lift\$5) and czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 14:23
S11 2	100	(si or silicon) near6 ion near2 beam and laser near5 (crystal\$7 or recrystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 14:23
S11 5	1098	crucible near2 (rais\$4 or lift\$5) near16melt near4 level and czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 14:24
S11 4	86	crucible near2 (rais\$4 or lift\$5) same melt near4 level and czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 14:24
S11 8	0	"5665159".pn. and cusp	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 15:13

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S11 7	0	"6077346".pn. and cusp	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 15:13
S11 6	69	crucible near2 (rais\$4 or lift\$5) near16 melt near4 level and czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	. OR	ON	2006/02/17 15:13
S12 1	35	S119 same czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 15:14
S12 0	97	S119 and czochralski	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 15:14
S11 9	675	cusp near2 magnetic near2 field	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/17 15:14
L11	27	electron near2 beam and 117/3.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:41
L12	2	"5795385".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:45
S77	22	(ion or plasma) near15 amorphous near10 (si or silicon) near15 hydrogen\$5 near5 ("no")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:46
S58	4	without near5 dehydrogen\$6 near15 (heat\$4 or anneal\$4) same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:46
L14	22	(ion or plasma) near15 amorphous near10 (si or silicon) near15 hydrogen\$5 near5 ("no")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:46

L13	4	without near5 dehydrogen\$6 near15 (heat\$4 or anneal\$4) same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 09:46
L28	2	"20010032589".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 10:13
L29	1	"20010032589".pn. and microcrystal\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 10:14
S8	592	(kirimura near2 hiroya or kiyoshi near2 ogata).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 10:33
L31	26	(kirimura near2 hiroya or kiyoshi near2 ogata).in. and laser near10 crystal\$7	·US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 10:34
L30	58	(kirimura near2 hiroya or kiyoshi near2 ogata).in. and laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/21 10:34